

# 3 A High Voltage Schottky Barrier Rectifier

#### **DESCRIPTION**

This UPS3100e3 in the Powermite3® package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3® package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

# KEY FEATURES

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

# ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

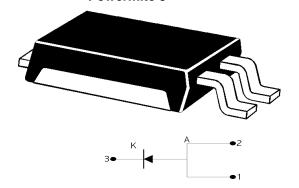
| Rating  | Symbol   | Value       | Unit |
|---|--|-------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage  | $egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$ | 100         | V    |
| RMS Reverse Voltage   | $V_{R(RMS)}$                                     | 70          | V    |
| Average Rectified Output Current  | Io   | 3           | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine wave Superimposed<br>on Rated Load@ T <sub>c</sub> =90 °C | I <sub>FSM</sub>                                 | 50          | А    |
| Storage Temperature   | $T_{STG}$  | -55 to +150 | °C   |
| Junction Temperature  | $T_J$  | -55 to +125 | °C   |

#### THERMAL CHARACTERISTICS

| Thermal Resistance        |                 |     |          |
|---------------------------|-----------------|-----|----------|
| Junction-to-Case (bottom) | $R_{\theta JC}$ | 2.5 | °C/ Watt |
| Junction to Ambient (1)   | Rain            | 65  | °C/ Watt |

(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print

## Powermite 3™



#### APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low I<sub>RM</sub>
- Small foot print 190 X 260 mils (1:1 Actual size)
  See mounting pad details on pg 3

#### **MECHANICAL & PACKAGING**

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S3100•
- WEIGHT: 0.072 gram (approx.)
- · Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

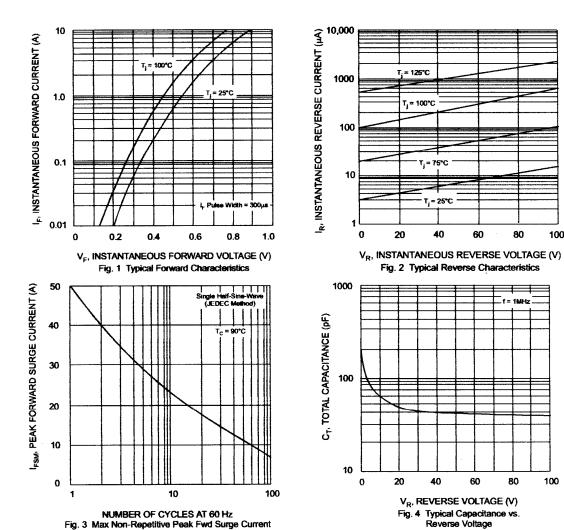
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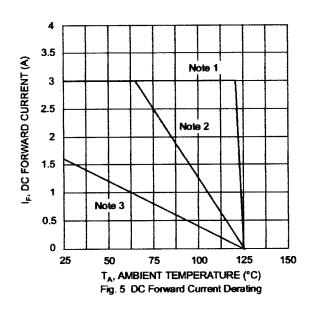
| D 4                        | 0 1 1                                 | 0 1141  | 2.5 | _    | 3.4  |       |
|----------------------------|---------------------------------------|---|-----|------|------|-------|
| Parameter                  | Symbol                                | Conditions  | Min | Тур. | Max  | Units |
|                            |                                       |   |     |      |      |       |
| Forward Voltage (Note 1)   |                                       | $I_F = 3 \text{ A}, T_j = 25 ^{\circ}\text{C}$    |     | 0.72 | 0.76 |       |
|                            | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | I <sub>F</sub> = 3 A , T <sub>j</sub> =100 °C     |     | 0.60 | 0.64 | V     |
|                            | V <sub>F</sub>                        | $I_F = 6 \text{ A}$ , $T_i = 25 ^{\circ}\text{C}$ |     | 0.79 | 0.83 | V     |
|                            |                                       | I <sub>F</sub> = 6 A , T <sub>i</sub> =100 °C     |     | 0.68 | 0.72 |       |
| Reverse Break Down Voltage |                                       |   |     |      |      |       |
| (Note 1)                   | $V_{BR}$                              | $I_R = 0.2 \text{ mA}$                            | 100 |      |      | V     |
| ,                          | DIX.                                  |   |     |      |      |       |
| Reverse Current (Note1)    |                                       | V <sub>R</sub> = 100V, T <sub>i</sub> = 25 °C     |     | 1.5  | 200  | μΑ    |
| ,                          | I <sub>F</sub>                        | V <sub>R</sub> = 100V, T <sub>i</sub> =100 °C     |     | 0.5  | 20   | mΑ    |
|                            |                                       | ,   |     |      |      |       |
| Capacitance                | C <sub>T</sub>                        | V <sub>R</sub> = 4 V: f = 1 MHz                   |     | 85   |      | pF    |

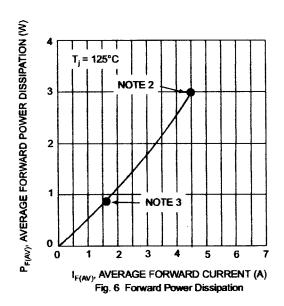
Note: 1 Short duration test pulse used to minimize self – heating effect.





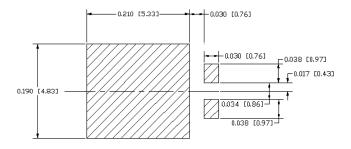
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- Notes: 1.  $T_A = T_{SOLDERING\ POINT}$ ,  $R_{\Theta JS} = 2.5 \text{C/W}$ ,  $R_{\Theta SA} = 0^{\circ} \text{C/W}$ .
  - 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper , double-sided , cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0".  $R_{\Theta JA}$  in range of 20-35°C/W.
  - 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta JA}$  in range of 65°C/W. See mounting pad below.

### **MOUNTING PAD DIMENSIONS**

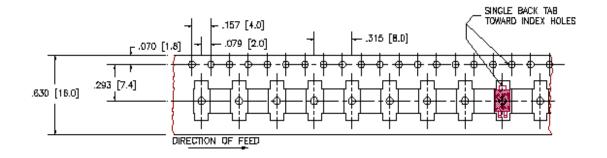


Mounting Pad Dimensions: inches [mm]

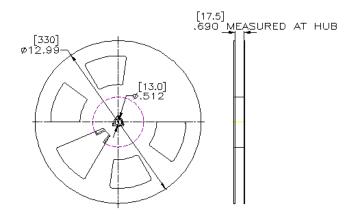


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### **TAPE & REEL**



### 13 INCH REEL

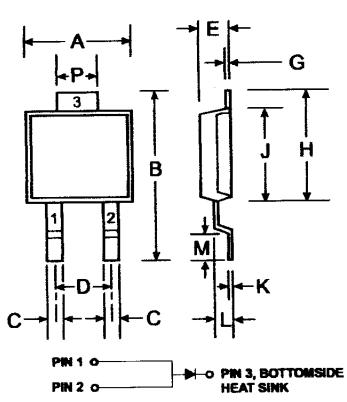


MECHANICA



# 3 A High Voltage Schottky Barrier Rectifier

## **PACKAGE DIMENSIONS**



| POWERMITE®3          |          |      |
|----------------------|----------|------|
| Dim                  | Min      | Max  |
| A                    | 4.03     | 4.09 |
| В                    | 6.40     | 6.61 |
| С                    | .889 NOM |      |
| D                    | 1.83 NOM |      |
| Ε                    | 1.10     | 1.14 |
| G                    | .178 NOM |      |
| Н                    | 5.01     | 5.17 |
| J                    | 4.37     | 4.43 |
| K                    | .178 NOM |      |
| L                    | .71      | .77  |
| M                    | .36      | .46  |
| Р                    | 1.73     | 1.83 |
| All Dimensions in mm |          |      |

Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

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